

## **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## IXTA182N055T

### • FEATURES

Static drain-source on-resistance:

 $R_{DS}(on) \le 5.0m_{\Omega}@V_{GS}=10V$ 

- · Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATION

SYMBOL

VDSS

 $V_{GS}$ 

lп

**I**DM

 $P_{D}$ 

Tj

Tstq

- DC/DC Converters
- High Current Switching Applications

Drain-Source Voltage

Gate-Source Voltage

Drain Current-Continuous

Drain Current-Single Pulsed

Total Dissipation @Tc=25°C

**Operating Junction Temperature** 

## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER

VALUE

55

 $\pm 20$ 

182

490

360

-55~175

-55~175

1

UNIT

V

V

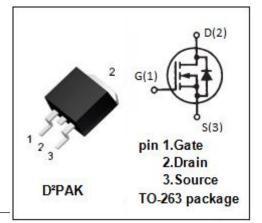
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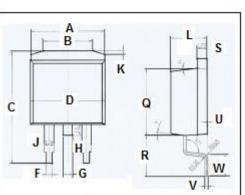
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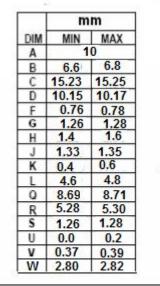
W

°C

°C







#### THERMAL CHARACTERISTICS

Storage Temperature

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	0.42	°C/W



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	55		V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 25A		5.0	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = ±20V; $V_{DS}$ =0V		±200	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	- μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		250	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 25A; V <sub>GS</sub> = 0V		1.0	V

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